











SN74LVC1G04

SCES214AD-APRIL1999-REVISED OCTOBER 2014

SN74LVC1G04 Single Inverter Gate

Features

- Available in the Ultra-Small 0.64-mm² Package (DPW) with 0.5-mm Pitch
- Supports 5-V V_{CC} Operation
- Inputs Accept Voltages up to 5.5 V Allowing Down Translation to V_{CC}
- Max t_{od} of 3.3 ns at 3.3-V
- Low Power Consumption, 10-µA Max I_{CC}
- ±24-mA Output Drive at 3.3-V
- I_{off} Supports Live-Insertion, Partial-Power-Down Mode, and Back-Drive Protection
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Protection Exceeds JESD 22
 - 2000-V Human-Body Model (A114-A)
 - 200-V Machine Model (A115-A)
 - 1000-V Charged-Device Model (C101)

Applications

- **AV Receiver**
- Audio Dock: Portable
- Blu-ray Player and Home Theater
- Embedded PC
- MP3 Player/Recorder (Portable Audio)
- Personal Digital Assistant (PDA)
- Power: Telecom/Server AC/DC Supply: Single Controller: Analog and Digital
- Solid State Drive (SSD): Client and Enterprise
- TV: LCD/Digital and High-Definition (HDTV)
- Tablet: Enterprise
- Video Analytics: Server
- Wireless Headset, Keyboard, and Mouse

Simplified Schematic



3 Description

single inverter gate is designed 1.65-V to 5.5-V V_{CC} operation.

The SN74LVC1G04 device performs the Boolean function $Y = \overline{A}$.

The CMOS device has high output drive while maintaining low static power dissipation over a broad V_{CC} operating range.

The SN74LVC1G04 device is available in a variety of packages, including the ultra-small DPW package with a body size of 0.8 mm × 0.8 mm.

Device Information⁽¹⁾

DEVICE NAME	PACKAGE	BODY SIZE
	SOT-23 (5)	2.9mm × 1.6mm
	SC70 (5)	2.0mm × 1.25mm
SN74LVC1G04	SON (6)	1.45mm × 1.0mm
	SON (6)	1.0mm × 1.0mm
	X2SON (4)	0.8mm × 0.8mm

(1) For all available packages, see the orderable addendum at the end of the datasheet.



Table of Contents

3 Descrip 4 Simplifi 5 Revisio 6 Pin Cor 7 Specific 7.1 Ab: 7.2 Ha 7.3 Re 7.4 The 7.5 Ele	ations 1 ption 1 fied Schematic 1 on History 2 nfiguration and Functions 3 cations 4 psolute Maximum Ratings 4 andling Ratings 4 percommended Operating Conditions 5 permal Information 5	10	Parameter Measurement Information Detailed Description 9.1 Overview 9.2 Functional Block Diagram 9.3 Feature Description 9.4 Device Functional Modes Application and Implementation 10.1 Application Information 10.2 Typical Application	10 10 10 10 11
4 Simplifi 5 Revisio 6 Pin Cor 7 Specific 7.1 Ab: 7.2 Ha 7.3 Re 7.4 The 7.5 Ele	ried Schematic	10	9.1 Overview 9.2 Functional Block Diagram 9.3 Feature Description 9.4 Device Functional Modes Application and Implementation 10.1 Application Information	10 10 10 10
 5 Revisio 6 Pin Cor 7 Specific 7.1 Abs 7.2 Ha 7.3 Re 7.4 The 7.5 Ele 	on History	10	9.3 Feature Description	10 10 11
6 Pin Cor 7 Specific 7.1 Abs 7.2 Ha 7.3 Re 7.4 Tho 7.5 Ele	nfiguration and Functions 3 cations 4 solute Maximum Ratings 4 andling Ratings 4 ecommended Operating Conditions 5 lermal Information 5	10	9.4 Device Functional Modes	10 11
7 Specific 7.1 Abs 7.2 Ha 7.3 Re 7.4 The 7.5 Ele	cations	10	Application and Implementation	11
7.1 Ab: 7.2 Ha 7.3 Re 7.4 The 7.5 Ele	osolute Maximum Ratings	10	10.1 Application Information	
7.2 Ha 7.3 Re 7.4 The 7.5 Ele	andling Ratings	44	• •	11
7.3 Re 7.4 The 7.5 Ele	ecommended Operating Conditions 5 ermal Information 5	44	10.2 Typical Application	
7.4 The 7.5 Ele	ermal Information5		10.2 Typical Application	11
7.5 Ele		. 11	Power Supply Recommendations	12
	ectrical Characteristics6		Layout	12
	vitching Characteristics, C _L = 15 pF		12.1 Layout Guidelines	
7.7 Sw	vitching Characteristics, $C_L = 30 \text{ pF or } 50 \text{ pF}$,		12.2 Layout Example	12
	0°C to 85°C6	13		
7.8 Sw	vitching Characteristics, C _L = 15 pF, –40°C to		13.1 Trademarks	
125	5°C6		13.2 Electrostatic Discharge Caution	13
	vitching Characteristics, C _L = 30 pF or 50 pF,		13.3 Glossary	
	0°C to 125°C	11	-	
7.10 O	Operating Characteristics7		Information	13

•	Updated Features, Description, and Device Information table.	
•	Added Pin Functions table.	
•	Added Thermal Information table.	
•	Added Detailed Description section.	10
•	Added Application and Implementation section.	1
•		
	Added Layout section.	
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	Changes from Revision AB (October 2013) to Revision AC	Pag
	Changes from Revision AB (October 2013) to Revision AC	Pag
CI	Changes from Revision AB (October 2013) to Revision AC Added Applications.	Pag
CI	Changes from Revision AB (October 2013) to Revision AC Added Applications. Added Device Information table.	Pag
CI	Changes from Revision AB (October 2013) to Revision AC Added Applications Added Device Information table Added DPW Package.	Pag

Changes from Revision AA (September 2013) to Revision AB

Page Removed Ordering Information table.

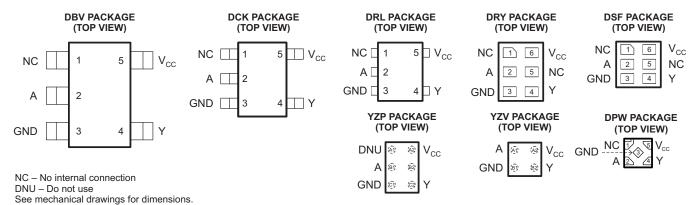
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Page



6 Pin Configuration and Functions



Pin Functions

		PIN				
NAME	DBV, DCK, DRL	DSF, DRY	YZP	YZV	DPW	DESCRIPTION
NC	1	1, 5	A1, B2	-	1	No connect
Α	2	2	B1	A1	2	Input
GND	3	3	C1	B1	3	Ground
Y	4	4	C2	B2	4	Output
V _{CC}	5	6	A2	A2	5	Power terminal

Product Folder Links: SN74LVC1G04



7 Specifications

7.1 Absolute Maximum Ratings⁽¹⁾

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT	
V _{CC}	Supply voltage range		-0.5	6.5	V	
V_{I}	Input voltage range		-0.5	6.5	V	
Vo	Voltage range applied to any output in the hig	age range applied to any output in the high-impedance or power-off state ⁽²⁾				
Vo	Voltage range applied to any output in the hig	-0.5	V _{CC} + 0.5	V		
I _{IK}	Input clamp current	V _I < 0		-50	mA	
I _{OK}	Output clamp current	V _O < 0		-50	mA	
Io	Continuous output current	Continuous output current				
	Continuous current through V _{CC} or GND	•				

⁽¹⁾ Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

7.2 Handling Ratings

	PARAMETER	DEFINITION	MIN	MAX	UNIT
T _{stg}		Storage temperature range	-65	150	°C
V _(ESD)	Clastroptotic discharge	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins ⁽¹⁾	0	2	14/
	Electrostatic discharge	Charged device model (CDM), per JEDEC specification JESD22-C101, all pins ⁽²⁾	0	1	kV

Product Folder Links: SN74LVC1G04

(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

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⁽²⁾ The input and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.

⁽³⁾ The value of V_{CC} is provided in the *Recommended Operating Conditions* table.

⁽¹⁾ JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.



7.3 Recommended Oprating Conditions⁽¹⁾

			MIN	MAX	UNIT	
.,	Cumply welfers	Operating	1.65	5.5		
V_{CC}	Supply voltage	Data retention only	1.5		V	
		V _{CC} = 1.65 V to 1.95 V	0.65 × V _{CC}			
.,	Supply voltage High-level input voltage Low-level input voltage Input voltage Output voltage High-level output current Low-level output current	V _{CC} = 2.3 V to 2.7 V	1.7		.,	
V_{IH}	High-level input voltage	V _{CC} = 3 V to 3.6 V	2		V	
		V _{CC} = 4.5 V to 5.5 V	0.7 × V _{CC}			
	Supply voltage High-level input voltage Low-level input voltage Input voltage Output voltage High-level output current Low-level output current	V _{CC} = 1.65 V to 1.95 V		0.35 × V _{CC}		
		V _{CC} = 2.3 V to 2.7 V		0.7	.,	
V_{IL}	Low-level input voltage	V _{CC} = 3 V to 3.6 V		0.8	V	
		V _{CC} = 4.5 V to 5.5 V		0.3 × V _{CC}		
VI	Input voltage		0	5.5	V	
Vo	Output voltage		0	V _{CC}	V	
		V _{CC} = 1.65 V		-4		
	Output voltage	V _{CC} = 2.3 V		-8		
I _{OH}	High-level output current			mA		
		V _{CC} = 3 V				
		V _{CC} = 4.5 V				
	Low-level input voltage Low-level input voltage Input voltage Output voltage High-level output current Low-level output current	V _{CC} = 1.65 V		4		
		V _{CC} = 2.3 V		8		
I _{OL}	Low-level output current			16	mA	
	,	V _{CC} = 3 V		24		
		V _{CC} = 4.5 V		32		
		V _{CC} = 1.8 V ± 0.15 V, 2.5 V ± 0.2 V		20		
Δt/Δν	Input transition rise or fall rate	V _{CC} = 3.3 V ± 0.3 V		10	ns/V	
		V _{CC} = 5 V ± 0.5 V		5		
T _A	Operating free-air temperature	,	-40	125	°C	

⁽¹⁾ All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

7.4 Thermal Information

<i>1</i> .	normal information							
				SN74L	VC1G04			
	THERMAL METRIC ⁽¹⁾	DBV	DCK	DRL	DRY	YZP	DPW	UNIT
		5 PINS	5 PINS	5 PINS	6 PINS	5 PINS	4 PINS	Ī
$R_{\theta JA}$	Junction-to-ambient thermal resistance	229	278	243	439	130	340	
R ₀ JCtop	Junction-to-case (top) thermal resistance	164	93	78	277	54	215	
$R_{\theta JB}$	Junction-to-board thermal resistance	62	65	78	271	51	294	°C/M
ψ_{JT}	Junction-to-top characterization parameter	44	2	10	84	1	41	°C/W
ψ_{JB}	Junction-to-board characterization parameter	62	64	77	271	50	294	
$R_{\theta JCbot}$	Junction-to-case (bottom) thermal resistance	-	-	-	-	-	250	

(1) For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report, SPRA953.

Product Folder Links: SN74LVC1G04



7.5 Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	V _{cc}	-40°	C to 85°C		MMENDED to 125°C	UNIT
			MIN	TYP ⁽¹⁾ MAX	MIN	TYP MAX	
	I _{OH} = -100 μA	1.65 V to 5.5 V	V _{CC} - 0.1		V _{CC} - 0.1		
	I _{OH} = -4 mA	1.65 V	1.2		1.2		
M	$I_{OH} = -8 \text{ mA}$	2.3 V	1.9		1.9		V
V_{OH}	I _{OH} = -16 mA	3 V	2.4		2.4		V
	I _{OH} = -24 mA	3 V	2.3		2.3		
	I _{OH} = -32 mA	4.5 V	3.8		3.8		
	I _{OL} = 100 μA	1.65 V to 5.5 V		0.1		0.1	
	I _{OL} = 4 mA	1.65 V		0.45		0.45	
V	I _{OL} = 8 mA	2.3 V		0.3		0.3	V
V _{OL}	I _{OL} = 16 mA	3 V		0.4		0.4	V
	I _{OL} = 24 mA	3 V		0.55		0.55	
	I _{OL} = 32 mA	4.5 V		0.55		0.55	
I _I A input	V _I = 5.5 V or GND	0 to 5.5 V		±5		±5	μA
I _{off}	V_I or $V_O = 5.5 \text{ V}$	0		±10		±10	μA
Icc	V _I = 5.5 V or GND I _O = 0	1.65 V to 5.5 V		10		10	μΑ
ΔI _{CC}	One input at $V_{CC} - 0.6 \text{ V}$, Other inputs at V_{CC} or GND	3 V to 5.5 V		500		500	μA
C _i	V _I = V _{CC} or GND	3.3 V		3.5		3.50	pF

⁽¹⁾ All typical values are at V_{CC} = 3.3 V, T_A = 25°C.

7.6 Switching Characteristics, $C_L = 15 pF$

over recommended operating free-air temperature range, $C_L = 15 \text{ pF}$ (unless otherwise noted) (see Figure 3)

						–40°C	to 85°C				
PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CC} = 1.8 V ± 0.15 V		V _{CC} = 2.5 V ± 0.2 V		V _{CC} = 3.3 V ± 0.3 V		V _{CC} = 5 V ± 0.5 V		UNIT
			MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t _{pd}	Α	Υ	2	6.4	1	4.2	0.7	3.3	0.7	3.1	ns

7.7 Switching Characteristics, $C_L = 30$ pF or 50 pF, -40° C to 85°C

over recommended operating free-air temperature range, C_L = 30 pF or 50 pF (unless otherwise noted) (see Figure 4)

						–40°C	to 85°C				
PARAMETE	FROM (INPUT)	TO (OUTPUT)	V _{CC} = 1.8 V ± 0.15 V		V _{CC} = 2.5 V ± 0.2 V		V _{CC} = 3.3 V ± 0.3 V		V _{CC} = 5 V ± 0.5 V		UNIT
			MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t _{pd}	А	Y	3	7.5	1.4	5.2	1	4.2	1	3.7	ns

7.8 Switching Characteristics, $C_L = 15 \text{ pF}$, -40°C to 125°C

over recommended operating free-air temperature range, C_L = 15 pF (unless otherwise noted) (see Figure 3)

						-40°C t	o 125°C				
PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CC} = 1.8 V ± 0.15 V		V _{CC} = 2.5 V ± 0.2 V		V _{CC} = 3.3 V ± 0.3 V		V _{CC} = 5 V ± 0.5 V		UNIT
			MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t _{pd}	A	Y	2	6.4	1	4.2	0.7	3.3	0.7	3.1	ns

Product Folder Links: SN74LVC1G04



7.9 Switching Characteristics, $C_L = 30 \text{ pF}$ or 50 pF, -40°C to 125°C

over recommended operating free-air temperature range, C_L = 30 pF or 50 pF (unless otherwise noted)

(see Figure 4)

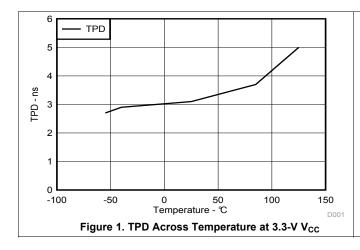
	FROM (INPUT)	TO (OUTPUT)		−40°C to 125°C									
PARAMETER			V _{CC} = 1.8 V ± 0.15 V		V _{CC} = 2.5 V ± 0.2 V		V _{CC} = 3.3 V ± 0.3 V		V _{CC} = 5 V ± 0.5 V		UNIT		
			MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX			
t _{pd}	Α	Y	3	7.5	1.4	5.2	1	4.2	1	3.7	ns		

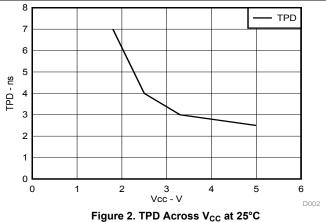
7.10 Operating Characteristics

over operating free-air temperature range (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	V _{CC} = 1.8 V	V _{CC} = 2.5 V	V _{CC} = 3.3 V	V _{CC} = 5.0 V	UNIT	
	PARAMETER	TEST CONDITIONS	TYP	TYP	TYP	TYP	UNIT	
C_{pd}	Power dissipation capacitance	f = 10 MHz	16	18	18	20	pF	

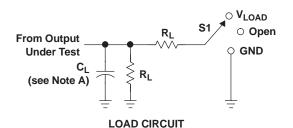
7.11 Typical Characteristics





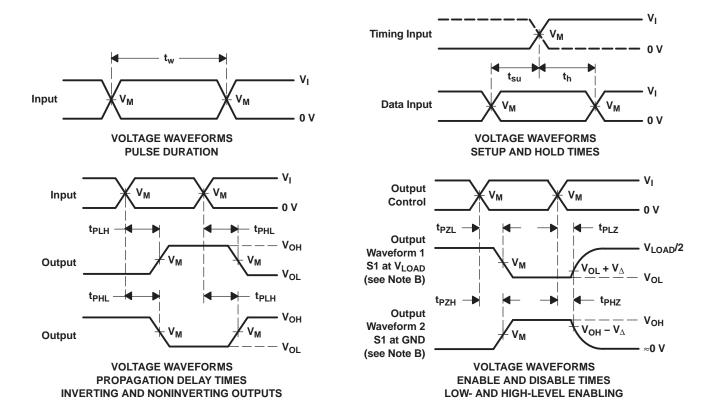


8 Parameter Measurement Information



TEST	S1
t _{PLH} /t _{PHL}	Open
t _{PLZ} /t _{PZL}	V _{LOAD}
t _{PHZ} /t _{PZH}	GND

	INF	PUTS	.,	.,		_	.,
V _{CC}	VI	t _r /t _f	V _M	V _{LOAD}	CL	R _L	V_{Δ}
1.8 V ± 0.15 V	V _{CC}	≤2 ns	V _{CC} /2	2×V _{CC}	15 pF	1 Μ Ω	0.15 V
2.5 V \pm 0.2 V	V _{CC}	≤2 ns	V _{CC} /2	2×V _{CC}	15 pF	1 M Ω	0.15 V
3.3 V \pm 0.3 V	3 V	≤2.5 ns	1.5 V	6 V	15 pF	1 M Ω	0.3 V
5 V \pm 0.5 V	V _{CC}	≤2.5 ns	V _{CC} /2	2×V _{CC}	15 pF	1 Μ Ω	0.3 V



NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR ≤ 10 MHz, Z_O = 50 Ω.
- D. The outputs are measured one at a time, with one transition per measurement.
- E. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
- F. t_{PZL} and t_{PZH} are the same as t_{en} .
- G. t_{PLH} and t_{PHL} are the same as t_{pd} .
- H. All parameters and waveforms are not applicable to all devices.

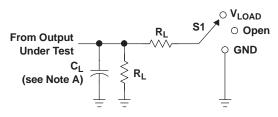
Figure 3. Load Circuit and Voltage Waveforms

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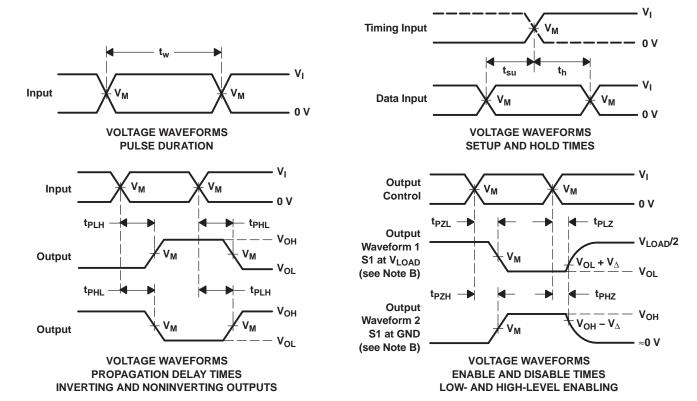
Parameter Measurement Information (continued)



TEST	S1
t _{PLH} /t _{PHL}	Open
t _{PLZ} /t _{PZL}	V _{LOAD}
t _{PHZ} /t _{PZH}	GND

LOAD CIRCUIT

.,	INF	PUTS	.,	.,		_	.,
V _{CC}	V_{I}	t _r /t _f	V _M	V _{LOAD}	CL	R _L	V_{Δ}
1.8 V ± 0.15 V	V _{CC}	≤2 ns	V _{CC} /2	2×V _{CC}	30 pF	1 k Ω	0.15 V
2.5 V \pm 0.2 V	V_{CC}	≤2 ns	V _{CC} /2	2×V _{CC}	30 pF	500 Ω	0.15 V
3.3 V \pm 0.3 V	3 V	≤2.5 ns	1.5 V	6 V	50 pF	500 Ω	0.3 V
5 V \pm 0.5 V	v_{cc}	≤2.5 ns	V _{CC} /2	2×V _{CC}	50 pF	500 Ω	0.3 V



- NOTES: A. C_L includes probe and jig capacitance.
 - B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
 - C. All input pulses are supplied by generators having the following characteristics: PRR ≤ 10 MHz, Z_O = 50 Ω.
 - D. The outputs are measured one at a time, with one transition per measurement.
 - E. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
 - F. t_{PZL} and t_{PZH} are the same as t_{en}.
 - G. t_{PLH} and t_{PHL} are the same as t_{pd} .
 - H. All parameters and waveforms are not applicable to all devices.

Figure 4. Load Circuit and Voltage Waveforms

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9 Detailed Description

9.1 Overview

The SN74LVC1G04 device contains inverter gate and performs the Boolean function $Y = \overline{A}$. This device is fully specified for partial-power-down applications using I_{off} . The I_{off} circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

The DPW package technology is a major breakthrough in IC packaging. Its tiny 0.64 mm square footprint saves significant board space over other package options while still retaining the traditional manufacturing friendly lead pitch of 0.5 mm.

9.2 Functional Block Diagram



9.3 Feature Description

- · Wide operating voltage range.
 - Operates from 1.65 V to 5.5 V.
- · Allows down voltage translation.
- Inputs accept voltages to 5.5 V.
- I_{off} feature allows voltages on the inputs and outputs, when V_{CC} is 0 V.

9.4 Device Functional Modes

Function Table

INPUT A	OUTPUT Y
Н	L
L	Н

Product Folder Links: SN74LVC1G04

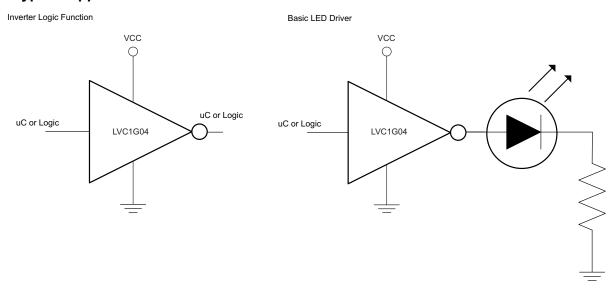


10 Application and Implementation

10.1 Application Information

The SN74LVC1G04 is a high drive CMOS device that can be used for implementing inversion logic with a high output drive, such as an LED application. It can produce 24 mA of drive current at 3.3~V making it Ideal for driving multiple outputs and good for high speed applications up to 100~Mhz. The inputs are 5.5~V tolerant allowing it to translate down to V_{CC} .

10.2 Typical Application



10.2.1 Design Requirements

This device uses CMOS technology and has balanced output drive. Care should be taken to avoid bus contention because it can drive currents that would exceed maximum limits. The high drive will also create fast edges into light loads so routing and load conditions should be considered to prevent ringing.

10.2.2 Detailed Design Procedure

- 1. Recommended Input Conditions
 - Rise time and fall time specs: See (Δt/ΔV) in the Recommended Operating Conditions table.
 - Specified high and low levels: See (V_{IH} and V_{IL}) in the Recommended Operating Conditions table.
 - Inputs are overvoltage tolerant allowing them to go as high as $(V_1 \text{ max})$ in the Recommended Operating Conditions table at any valid V_{CC} .

2. Recommend Output Conditions

- Load currents should not exceed (I_O max) per output and should not exceed total current (continuous current through V_{CC} or GND) for the part. These limits are located in the Absolute Maximum Ratings table.
- Outputs should not be pulled above V_{CC}.

Product Folder Links: SN74LVC1G04



Typical Application (continued)

10.2.3 Application Curves

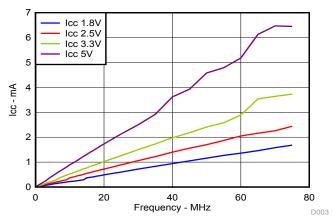


Figure 5. I_{CC} vs Frequency

11 Power Supply Recommendations

The power supply can be any voltage between the min and max supply voltage rating located in the Recommended Operating Conditions table.

Each VCC pin should have a good bypass capacitor to prevent power disturbance. For devices with a single supply, a 0.1-µF capacitor is recommended. if there are multiple VCC pins, then a 0.01-µF or 0.022-µF capacitor is recommended for each power pin. It is ok to parallel multiple bypass capacitors to reject different frequencies of noise. 0.1-µF and 1-µF capacitors are commonly used in parallel. The bypass capacitor should be installed as close to the power pin as possible for best results.

12 Layout

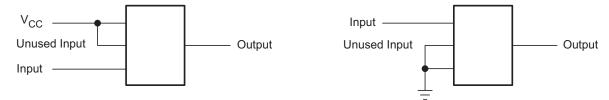
12.1 Layout Guidelines

When using multiple bit logic devices, inputs should never float.

In many cases, functions or parts of functions of digital logic devices are unused; for example, when only two inputs of a triple-input AND gate are used or only 3 of the 4 buffer gates are used. Such input pins should not be left unconnected because the undefined voltages at the outside connections result in undefined operational states. The rules that must be observed under all circumstances are specified in the next paragraph.

All unused inputs of digital logic devices must be connected to a high or low bias to prevent them from floating. The logic level that should be applied to any particular unused input depends on the function of the device. Generally they will be tied to GND or VCC; whichever makes more sense or is more convenient.

12.2 Layout Example



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Product Folder Links: SN74LVC1G04



13 Device and Documentation Support

13.1 Trademarks

All trademarks are the property of their respective owners.

13.2 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

13.3 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms and definitions.

14 Mechanical, Packaging, and Orderable Information

The following pages include mechanical packaging and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

Product Folder Links: SN74LVC1G04





28-Oct-2017

PACKAGING INFORMATION

Orderable Device	Status	Package Type	_	Pins	_		Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	(6)	(3)		(4/5)	
SN74LVC1G04DBVR	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	(C045, C04F, C04K, C04R) (C04H, C04P)	Samples
SN74LVC1G04DBVRE4	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	(C045, C04F, C04K, C04R) (C04H, C04P)	Samples
SN74LVC1G04DBVRG4	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	(C045, C04F, C04K, C04R) (C04H, C04P)	Samples
SN74LVC1G04DBVT	ACTIVE	SOT-23	DBV	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	(C045, C04F, C04K, C04R) (C04H, C04P, C04S)	Samples
SN74LVC1G04DBVTE4	ACTIVE	SOT-23	DBV	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	(C045, C04F, C04K, C04R) (C04H, C04P, C04S)	Samples
SN74LVC1G04DBVTG4	ACTIVE	SOT-23	DBV	5	250	TBD	Call TI	Call TI	-40 to 125	(C045, C04F, C04K, C04R) (C04H, C04P, C04S)	Samples
SN74LVC1G04DCKR	ACTIVE	SC70	DCK	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	(CC5, CCF, CCK, CC R) (CCH, CCP, CCS)	Samples
SN74LVC1G04DCKRE4	ACTIVE	SC70	DCK	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	(CC5, CCF, CCK, CC R) (CCH, CCP, CCS)	Samples
SN74LVC1G04DCKRG4	ACTIVE	SC70	DCK	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	(CC5, CCF, CCK, CC R) (CCH, CCP, CCS)	Samples
SN74LVC1G04DCKT	ACTIVE	SC70	DCK	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	(CC5, CCF, CCK, CC R) (CCH, CCP)	Samples
SN74LVC1G04DCKTE4	ACTIVE	SC70	DCK	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	(CC5, CCF, CCK, CC R) (CCH, CCP)	Samples



PACKAGE OPTION ADDENDUM

28-Oct-2017

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
SN74LVC1G04DCKTG4	ACTIVE	SC70	DCK	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	(CC5, CCF, CCK, CC R) (CCH, CCP)	Samples
SN74LVC1G04DPWR	ACTIVE	X2SON	DPW	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	K4	Samples
SN74LVC1G04DRLR	ACTIVE	SOT-5X3	DRL	5	4000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	(CC7, CCR)	Samples
SN74LVC1G04DRLRG4	ACTIVE	SOT-5X3	DRL	5	4000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	(CC7, CCR)	Samples
SN74LVC1G04DRY2	ACTIVE	SON	DRY	6	5000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	CC	Samples
SN74LVC1G04DRYR	ACTIVE	SON	DRY	6	5000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	CC	Samples
SN74LVC1G04DRYRG4	ACTIVE	SON	DRY	6	5000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	CC	Samples
SN74LVC1G04DSF2	ACTIVE	SON	DSF	6	5000	Green (RoHS & no Sb/Br)	CU NIPDAU CU NIPDAUAG	Level-1-260C-UNLIM	-40 to 85	CC	Samples
SN74LVC1G04DSFR	ACTIVE	SON	DSF	6	5000	Green (RoHS & no Sb/Br)	CU NIPDAU CU NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	CC	Samples
SN74LVC1G04YZPR	ACTIVE	DSBGA	YZP	5	3000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 85	(CC7, CCN)	Samples
SN74LVC1G04YZVR	ACTIVE	DSBGA	YZV	4	3000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 85	CC 7	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.





28-Oct-2017

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead/Ball Finish Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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OTHER QUALIFIED VERSIONS OF SN74LVC1G04:

Automotive: SN74LVC1G04-Q1

■ Enhanced Product: SN74LVC1G04-EP

NOTE: Qualified Version Definitions:

- Automotive Q100 devices qualified for high-reliability automotive applications targeting zero defects
- Enhanced Product Supports Defense, Aerospace and Medical Applications

PACKAGE MATERIALS INFORMATION

www.ti.com 28-Dec-2017

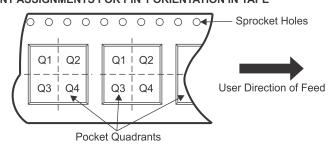
TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



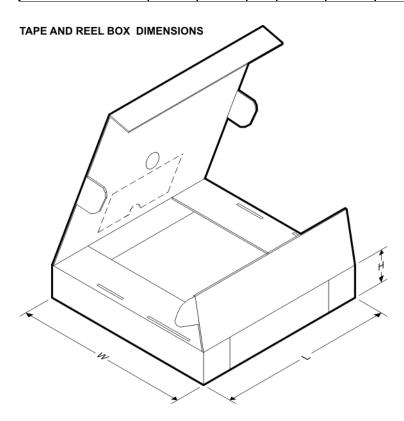
*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74LVC1G04DBVR	SOT-23	DBV	5	3000	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
SN74LVC1G04DBVR	SOT-23	DBV	5	3000	180.0	8.4	3.23	3.17	1.37	4.0	8.0	Q3
SN74LVC1G04DBVR	SOT-23	DBV	5	3000	178.0	9.2	3.3	3.23	1.55	4.0	8.0	Q3
SN74LVC1G04DBVT	SOT-23	DBV	5	250	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
SN74LVC1G04DBVT	SOT-23	DBV	5	250	178.0	9.2	3.3	3.23	1.55	4.0	8.0	Q3
SN74LVC1G04DCKR	SC70	DCK	5	3000	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
SN74LVC1G04DCKR	SC70	DCK	5	3000	178.0	9.2	2.4	2.4	1.22	4.0	8.0	Q3
SN74LVC1G04DCKT	SC70	DCK	5	250	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
SN74LVC1G04DCKT	SC70	DCK	5	250	178.0	9.2	2.4	2.4	1.22	4.0	8.0	Q3
SN74LVC1G04DCKT	SC70	DCK	5	250	180.0	9.2	2.3	2.55	1.2	4.0	8.0	Q3
SN74LVC1G04DPWR	X2SON	DPW	5	3000	178.0	8.4	0.91	0.91	0.5	2.0	8.0	Q3
SN74LVC1G04DRLR	SOT-5X3	DRL	5	4000	180.0	9.5	1.78	1.78	0.69	4.0	8.0	Q3
SN74LVC1G04DRLR	SOT-5X3	DRL	5	4000	180.0	8.4	1.98	1.78	0.69	4.0	8.0	Q3
SN74LVC1G04DRY2	SON	DRY	6	5000	180.0	9.5	1.6	1.15	0.75	4.0	8.0	Q3
SN74LVC1G04DRY2	SON	DRY	6	5000	180.0	8.4	1.65	1.2	0.7	4.0	8.0	Q3
SN74LVC1G04DRYR	SON	DRY	6	5000	180.0	9.5	1.15	1.6	0.75	4.0	8.0	Q1
SN74LVC1G04DSF2	SON	DSF	6	5000	180.0	9.5	1.16	1.16	0.5	4.0	8.0	Q3
SN74LVC1G04DSFR	SON	DSF	6	5000	180.0	9.5	1.16	1.16	0.5	4.0	8.0	Q2

PACKAGE MATERIALS INFORMATION

www.ti.com 28-Dec-2017

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74LVC1G04YZPR	DSBGA	YZP	5	3000	178.0	9.2	1.02	1.52	0.63	4.0	8.0	Q1
SN74LVC1G04YZVR	DSBGA	YZV	4	3000	180.0	8.4	1.0	1.0	0.63	2.0	8.0	Q1



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74LVC1G04DBVR	SOT-23	DBV	5	3000	180.0	180.0	18.0
SN74LVC1G04DBVR	SOT-23	DBV	5	3000	202.0	201.0	28.0
SN74LVC1G04DBVR	SOT-23	DBV	5	3000	180.0	180.0	18.0
SN74LVC1G04DBVT	SOT-23	DBV	5	250	180.0	180.0	18.0
SN74LVC1G04DBVT	SOT-23	DBV	5	250	180.0	180.0	18.0
SN74LVC1G04DCKR	SC70	DCK	5	3000	180.0	180.0	18.0
SN74LVC1G04DCKR	SC70	DCK	5	3000	180.0	180.0	18.0
SN74LVC1G04DCKT	SC70	DCK	5	250	180.0	180.0	18.0
SN74LVC1G04DCKT	SC70	DCK	5	250	180.0	180.0	18.0
SN74LVC1G04DCKT	SC70	DCK	5	250	205.0	200.0	33.0
SN74LVC1G04DPWR	X2SON	DPW	5	3000	205.0	200.0	33.0
SN74LVC1G04DRLR	SOT-5X3	DRL	5	4000	184.0	184.0	19.0
SN74LVC1G04DRLR	SOT-5X3	DRL	5	4000	202.0	201.0	28.0
SN74LVC1G04DRY2	SON	DRY	6	5000	184.0	184.0	19.0
SN74LVC1G04DRY2	SON	DRY	6	5000	202.0	201.0	28.0



PACKAGE MATERIALS INFORMATION

www.ti.com 28-Dec-2017

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74LVC1G04DRYR	SON	DRY	6	5000	184.0	184.0	19.0
SN74LVC1G04DSF2	SON	DSF	6	5000	184.0	184.0	19.0
SN74LVC1G04DSFR	SON	DSF	6	5000	184.0	184.0	19.0
SN74LVC1G04YZPR	DSBGA	YZP	5	3000	220.0	220.0	35.0
SN74LVC1G04YZVR	DSBGA	YZV	4	3000	210.0	185.0	35.0



Images above are just a representation of the package family, actual package may vary. Refer to the product data sheet for package details.

4073253/P





SMALL OUTLINE TRANSISTOR



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. Reference JEDEC MO-178.



SMALL OUTLINE TRANSISTOR



NOTES: (continued)

- 4. Publication IPC-7351 may have alternate designs.
- 5. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE TRANSISTOR



NOTES: (continued)

- 6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 7. Board assembly site may have different recommendations for stencil design.



DRL (R-PDSO-N5)

PLASTIC SMALL OUTLINE



NOTES:

- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M—1994.
- B. This drawing is subject to change without notice.
- Body dimensions do not include mold flash, interlead flash, protrusions, or gate burrs.

 Mold flash, interlead flash, protrusions, or gate burrs shall not exceed 0,15 per end or side.
- D. JEDEC package registration is pending.



DRL (R-PDSO-N5)

PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Customers should contact their board fabrication site for minimum solder mask web tolerances between signal pads.
- E. Maximum stencil thickness 0,127 mm (5 mils). All linear dimensions are in millimeters.
- F. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
- G. Side aperture dimensions over—print land for acceptable area ratio > 0.66. Customer may reduce side aperture dimensions if stencil manufacturing process allows for sufficient release at smaller opening.





NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. Reference JEDEC registration MO-287, variation X2AAF.





PLASTIC SMALL OUTLINE NO-LEAD



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Customers should contact their board fabrication site for minimum solder mask web tolerances between signal pads. If 2 mil solder mask is outside PCB vendor capability, it is advised to omit solder mask.
- E. Maximum stencil thickness 0,1016 mm (4 mils). All linear dimensions are in millimeters.
- F. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
- G. Suggest stencils cut with lasers such as Fiber Laser that produce the greatest positional accuracy.
- H. Component placement force should be minimized to prevent excessive paste block deformation.



DCK (R-PDSO-G5)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
- D. Falls within JEDEC MO-203 variation AA.



DCK (R-PDSO-G5)

PLASTIC SMALL OUTLINE



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
- D. Publication IPC-7351 is recommended for alternate designs.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.





Images above are just a representation of the package family, actual package may vary. Refer to the product data sheet for package details.







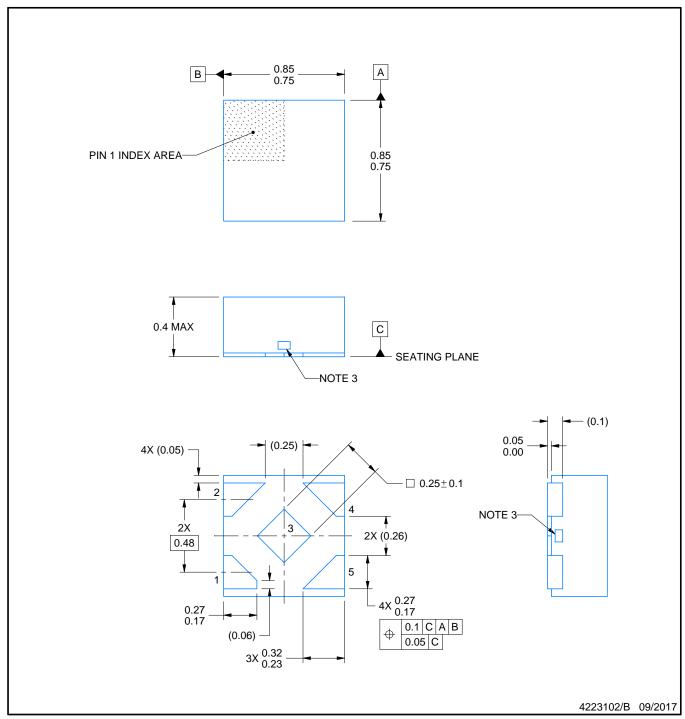
Images above are just a representation of the package family, actual package may vary. Refer to the product data sheet for package details.

4211218-3/D





PLASTIC SMALL OUTLINE - NO LEAD



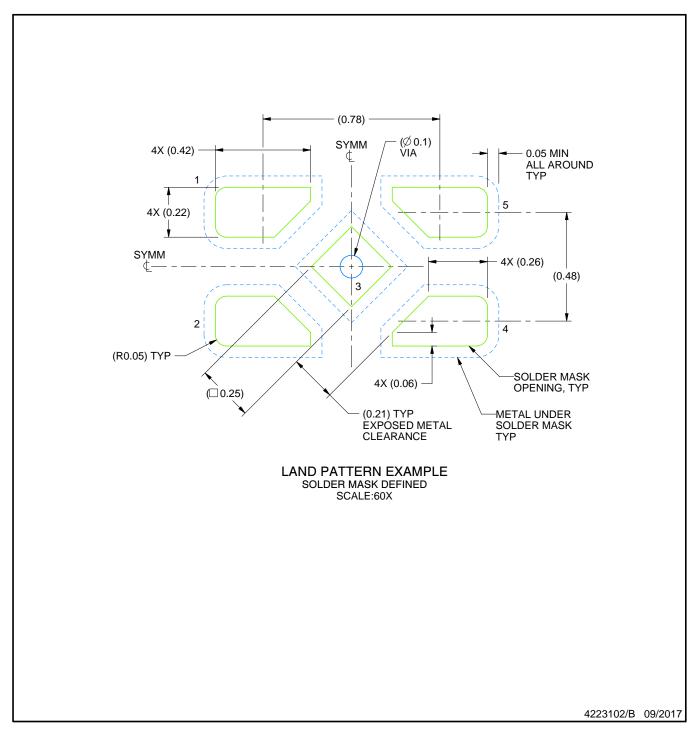
NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.
- 3. The size and shape of this feature may vary.



PLASTIC SMALL OUTLINE - NO LEAD

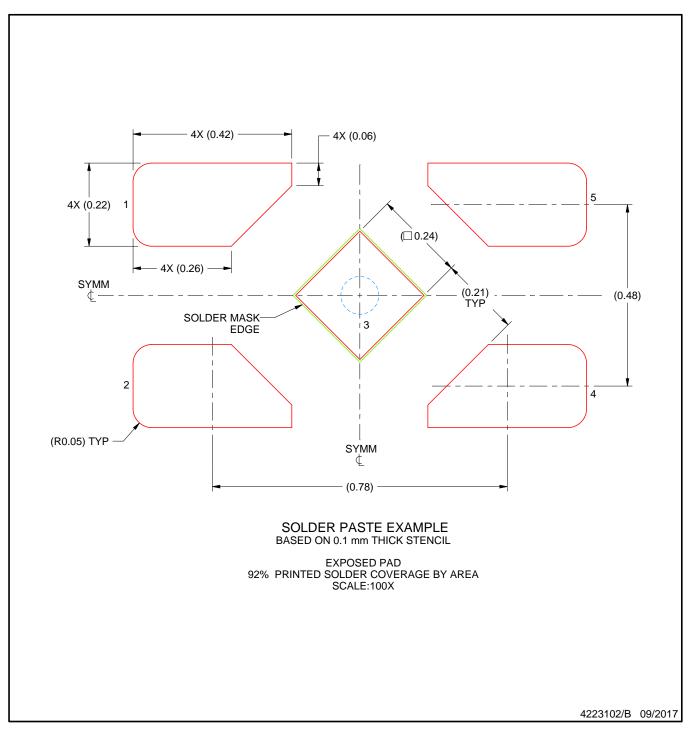


NOTES: (continued)

4. This package is designed to be soldered to a thermal pad on the board. For more information, refer to QFN/SON PCB application note in literature No. SLUA271 (www.ti.com/lit/slua271).



PLASTIC SMALL OUTLINE - NO LEAD



NOTES: (continued)

5. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.





DIE SIZE BALL GRID ARRAY



NOTES:

- All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.



DIE SIZE BALL GRID ARRAY



NOTES: (continued)

3. Final dimensions may vary due to manufacturing tolerance considerations and also routing constraints. For more information, see Texas Instruments literature number SNVA009 (www.ti.com/lit/snva009).



DIE SIZE BALL GRID ARRAY



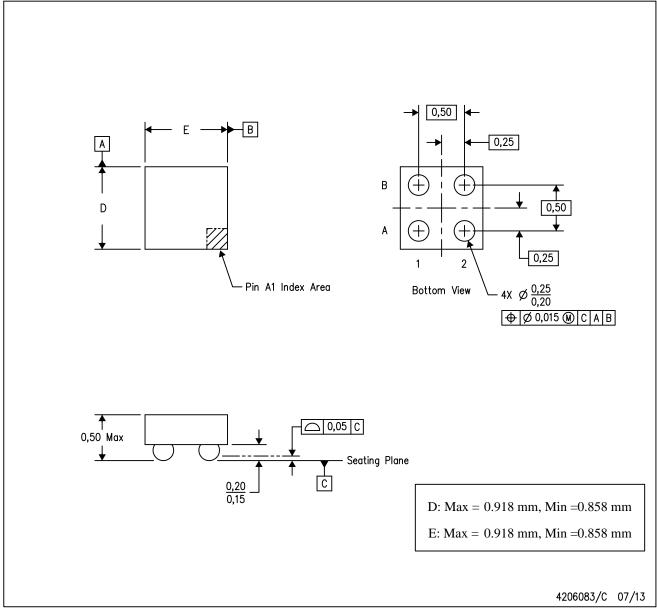
NOTES: (continued)

4. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release.



YZV (S-XBGA-N4)

DIE-SIZE BALL GRID ARRAY



NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M—1994.

- B. This drawing is subject to change without notice.
- C. NanoFree™ package configuration.

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TI may expressly designate certain products as completing a particular qualification (e.g., Q100, Military Grade, or Enhanced Product). Designers agree that it has the necessary expertise to select the product with the appropriate qualification designation for their applications and that proper product selection is at Designers' own risk. Designers are solely responsible for compliance with all legal and regulatory requirements in connection with such selection.

Designer will fully indemnify TI and its representatives against any damages, costs, losses, and/or liabilities arising out of Designer's non-compliance with the terms and provisions of this Notice.